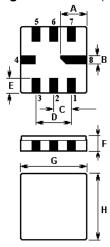


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Email: info@actcrystals.com

The ACTQ0015/915.0/QCC8C is a two-port, 180° surface-acoustic-wave (SAW) resonator in a surface-mount ceramic QCC8C case. It provides reliable, fundamental-mode, quartz frequency stabilization i.e. in transmitters or local oscillators operating at 915.000 MHz.

1.Package Dimension (QCC8C)

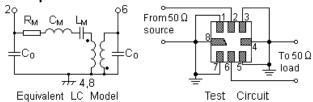


2.

Pin	Configuration			
2	Input / output			
6	Input / output			
4,8	Case Ground			
1,3,5,7	NC			

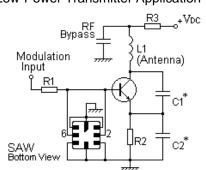
Sign	Data (unit: mm)	Sign	Data (unit: mm)
Α	2.08	Е	1.2
В	0.6	F	1.35
С	1.27	G	5.0
D	2.54	Н	5.0

3. Equivalent LC Model and Test Circuit

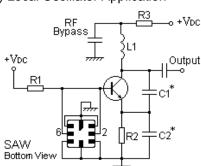


4. Typical Application Circuits

1) Low-Power Transmitter Application



2) Local Oscillator Application



Issue: 1 C1

Date: SEPT 04

In keeping with our ongoing policy of product evolvement and improvement, the above specification is subject to change without notice.

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For quotations or further information please contact us at:

3 The Business Centre, Molly Millars Lane, Wokingham, Berks, RG41 2EY, UK

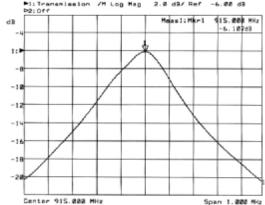
http://www.actcrystals.com



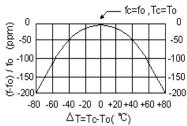
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Email: info@actcrystals.com

5. Typical Frequency Response



6.Temperature Characteristics



The curve shown above accounts for resonator contribution only and does not include LC component temperature characteristics.

7.Performance

7-1.Maximum Ratings

Rating		Value	Unit
CW RF Power Dissipation	P	10	dBm
DC Voltage Between Terminals	$V_{\rm DC}$	±30	V
Storage Temperature Range	\mathcal{T}_{stg}	-40 to +85	°C
Operating Temperature Range	T _A	-10 to +60	°C

7-2. Electronic Characteristics

	Characteristics	Sym	Minimum	Typical	Maximum	Unit				
Centre Frequency (+25°C)	Absolute Frequency	fc	914.850		915.150	MHz				
	Tolerance from 915.000 MHz	Δf_C		±150		kHz				
Insertion Loss		IL		7.0	9.0	dB				
Quality Factor	Unloaded Q	Q _U		7,230						
	50 Ω Loaded Q	Q_L		4,000						
	Turnover Temperature	T ₀	25		55	°C				
Temperature Stability	Turnover Frequency	f ₀		fc		kHz				
	Frequency Temperature Coefficient	FTC		0.032		ppm/°C				
Frequency Aging - Absolute Value during the First Year		f _A		≤10		ppm/yr				
DC Insulation Resistance Between Any Two Terminals			1.0			МΩ				
RF Equivalent RLC Model	Motional Resistance	R _M		124	182	Ω				
	Motional Inductance	L _M		155.9291		μН				
	Motional Capacitance	См		0.1942		fF				
	Shunt Static Capacitance	C ₀	1.10	1.35	1.60	pF				

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1 CAUTION: Electrostatic Sensitive Device. Observe precautions for handling!

- 1. The frequency f_C is the frequency of minimum IL with the resonator in the specified test fixture in a 50 Ω test system with VSWR≤1.2:1.
- Unless noted otherwise, case temperature T_C = +25°C±2°C.
- Frequency aging is the change in f_C with time and is specified at +65°C or less. Aging may exceed the specification for prolonged temperatures above +65°C. Typically, aging is greatest the first year after manufacture, decreasing in subsequent years.
- Turnover temperature, T₀, is the temperature of maximum (or turnover) frequency, f₀. The nominal frequency at any case temperature, T₀, may be calculated from: f = f₀ [1 FTC (T₀ T₀)²].
 This equivalent RLC model approximates resonator performance near the resonant frequency and is provided
- 5. This equivalent RLC model approximates resonator performance near the resonant frequency and is provided for reference only. The capacitance C₀ is the measured static (non-motional) capacitance between input terminal and ground or output terminal and ground. The measurement includes case parasitic capacitance.
- 6. Derived mathematically from one or more of the following directly measured parameters: f_C, IL, 3 dB bandwidth, f_C versus T_C, and C₀.
- The specifications of this device are based on the test circuit shown above and subject to change or obsolescence without notice.
- 8. Typically, equipment utilizing this device requires emissions testing and government approval, which is the responsibility of the equipment manufacturer.
- 9. Our liability is only assumed for the Surface Acoustic Wave (SAW) component(s) per se, not for applications, processes and circuits implemented within components or assemblies.

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